查询MAX4736供应商

19-2382; Rev 0; 4/02

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0.8Ω, Low-Voltage, Single-Supply, Dual SPDT Analog Switch

General Description

The MAX4736 is a low on-resistance, low-voltage, dual single-pole/double throw (SPDT) analog switch that operates from a single 1.6V to 3.6V supply. This device has fast switching speeds ($t_{ON} = 25ns$, $t_{OFF} = 20ns$ max), handles Rail-to-Rail[®] analog signals, and consumes less than 4µW of quiescent power. The MAX4736 has break-before-make switching.

When powered from a 3V supply, the MAX4736 features low 0.8Ω (max) on-resistance (R_{ON}), with 0.2Ω (max) R_{ON} matching and 0.1Ω R_{ON} flatness. The digital logic input is 1.8V CMOS compatible when using a single 3V supply.

The MAX4736 has one normally open (NO) switch and one normally closed (NC) switch, and is available in 12-pin QFN and 10-pin µMAX packages.

Applications

Power Routing

Battery-Powered Systems

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

PCMCIA Cards

Cellular Phones

Modems

Hard Drives

Low RON 0.8Ω max (3V Supply) 2Ω max (1.8V Supply)

0.1Ω max Ron Flatness (3V Supply)

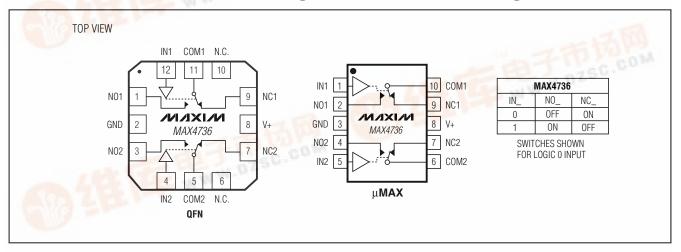
- ♦ 1.6V to 3.6V Single-Supply Operation
- ♦ Available in QFN and µMAX Packages
- High-Current Handling Capacity (150mA Continuous)
- 1.8V CMOS Logic Compatible (3V Supply)
- Fast Switching: ton = 25ns, toFF = 20ns



Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4736EUB	-40°C to +85°C	10 µMAX
MAX4736EGC	-40°C to +85°C	12 QFN
1 1.20	WW.	DZSU

Pin Configurations/Functional Diagrams/Truth Table



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.



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Features

ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to GND)

V+, IN	0.3V to +4V
COM_, NO_, NC_ (Note 1)	0.3V to (V+ + 0.3V)
Continuous Current COM_, NO_, NC	±150mA
Continuous Current (all other pins)	±20mA
Peak Current COM_, NO_, NC_	
(pulsed at 1ms 10% duty cycle)	±300mA

Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single 3V Supply

(V+ = 2.7V to 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified. Typical values are at V+ = 3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	МАХ	UNITS	
ANALOG SWITCH								
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On Desistance (Note 4)	Devi	$V_{+} = 2.7V_{,}$	+25°C		0.6	0.8		
On-Resistance (Note 4)	Resistance (Note 4) R_{ON} $I_{COM_}$ = 100mA; $V_{NO_}$ or $V_{NC_}$ = 1.5V		$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			1	Ω	
On-Resistance Match		$V_{+} = 2.7V,$	+25°C		0.1	0.2		
(Notes 4, 5)	etween Channels ΔR_{ON} $I_{COML} = 100 \text{mA};$ Notes 4, 5) $V_{NO_{-}} \text{ or } V_{NC_{-}} = 1.5 \text{V}$		$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$		0.3		Ω	
On-Resistance Flatness	Devices	$V_{+} = 2.7V,$	+25°C		0.05	0.1	Ω	
(Note 6)	R _{FLAT} (ON)	I _{COM} = 100mA; V _{NO} or V _{NC} = 1V, 1.5V, 2V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$		0.2			
NO_ or NC_ Off-Leakage	I _{NO_} (OFF),	V+ = 3.6V,	+25°C	-1	±0.002	+1		
Current (Note 10)	INC_(OFF)	V _{COM} _ = 0.3V, 3.3V; V _{NO} _ or V _{NC} _ = 3.3V, 0.3V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-5		+5	nA	
COM_ On-Leakage Current		V+ = 3.6V, V _{COM} _ = 0.3V, 3.3V;	+25°C	-2	±0.002	+2		
(Note 10)	ICOM_(ON)	$V_{NO_{-}}$ or $V_{NC_{-}} = 0.3V$, 3.3V, or floating	T _{MIN} to T _{MAX}	-10		+10	nA	

ELECTRICAL CHARACTERISTICS—Single 3V Supply (continued)

(V+ = 2.7V to 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified. Typical values are at V+ = 3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS	
SWITCH DYNAMIC CHARACTE	RISTICS		I				I	
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.5V;$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		20	25	ns	
		Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			30		
Turn-Off Time	toff	$V_{NO_{-}}, V_{NC_{-}} = 1.5V;$ R _L = 50 Ω , C _L = 35pF,	+25°C		15	20	ns	
	-	Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			25		
Break-Before-Make (Note 7)	topu	$V_{NO_{-}}, V_{NC_{-}} = 1.5V;$	+25°C		5		ns	
Dieak-Deiole-Make (Note 7)	tввм	$R_L = 50\Omega$, $C_L = 35pF$, Figure 2	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	1				
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 3	+25°C		60		рС	
NO_ or NC_ Off-Capacitance	C _{OFF}	f = 1MHz, Figure 4	+25°C		33		pF	
COM_ Off-Capacitance	CCOM(OFF)	COM(OFF) f = 1MHz, Figure 4			60		рF	
COM_ On-Capacitance	CCOM(ON)	f = 1MHz, Figure 4	+25°C		85		pF	
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$, $C_L = 5pF$, Figure 5			130		MHz	
Off-Isolation (Note 8)	VISO	$ f = 1 MHz, V_{COM_} = 1 V_{P.P}, R_{L} = 50 \Omega, C_{L} = 5 pF, Figure 5 $	+25°C		-52		dB	
Crosstalk (Note 9)	V _{CT}	$f = 1MHz, V_{COM} = 1V_{P,P}, R_L = 50\Omega, C_L = 5pF, Figure 5$	+25°C		-78		dB	
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, $V_{COM_{-}}$ = 2 V_{P-P} , R_{L} = 32 Ω	+25°C		0.018		%	
LOGIC INPUT (A_, IN_)								
Input Logic High VIH				1.4			V	
Input Logic Low	VIL					0.5	V	
Input Leakage Current	I _{IN}	$V_{IN_{}} = 0 \text{ or } 3.6V$		-1	+0.005	+1	μΑ	
POWER SUPPLY								
Power-Supply Range	V+			1.6		3.6	V	
Positive Supply Current	l+	$V + = 3.6V$, $V_{IN} = 0$ or $V +$, all channels on or off			0.006	1	μA	

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ELECTRICAL CHARACTERISTICS—Single 1.8V Supply

 $(V + = 1.8V, V_{IH} = 1.0V, V_{IL} = 0.4V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	Ron	$I_{COM} = 10 \text{mA};$	+25°C		1.5	2	Ω
	HON	V_{NO} or V_{NC} = 1V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			3	22
SWITCH DYNAMIC CHARACT	ERISTICS						T
Turn-On Time	ton	$V_{NO_{-}}$ or $V_{NC_{-}} = 1V$; RI = 50 Ω , CI = 35pF,	+25°C		25	30	
rum-on nine	UN	Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			35	ns
Turne Off Time -	$V_{NO_{-}}$ or $V_{NC_{-}} = 1V;$		+25°C		18	25	
Turn-Off Time	tOFF	$R_L = 50\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			28	ns
Break-Before-Make (Note 7)	toout	$V_{NO_{-}}$ or $V_{NC_{-}} = 1V$; RL = 50 Ω , CL = 35pF,	+25°C		7		ns
DIEAR-DEIDIE-IVIARE (NOLE 7)	tввм	Figure 2 Figure 2	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	1			
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1nF$, Figure 3	+25°C		35		рС
Off-Isolation (Note 8)	V _{ISO}	f = 1MHz, V _{NO} = V _{NC} = 1V _{P-} P, R _L = 50Ω, C _L = 5pF, Figure 5	+25°C		-52		dB
Crosstalk (Note 9)	V _{CT}	$ f = 1 MHz, V_{COM} = 1 V_{P-P}, \\ R_L = 50 \Omega, C_L = 5 pF, Figure 5 $	+25°C		-78		dB
LOGIC INPUT (IN_)							
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	l _{IN}	$V_{IN_{-}} = 0 \text{ or } 3.6V$				1	μA

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

Note 3: -40°C specifications are guaranteed by design.

Note 4: R_{ON} and ΔR_{ON} matching specifications for QFN packaged parts are guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$.

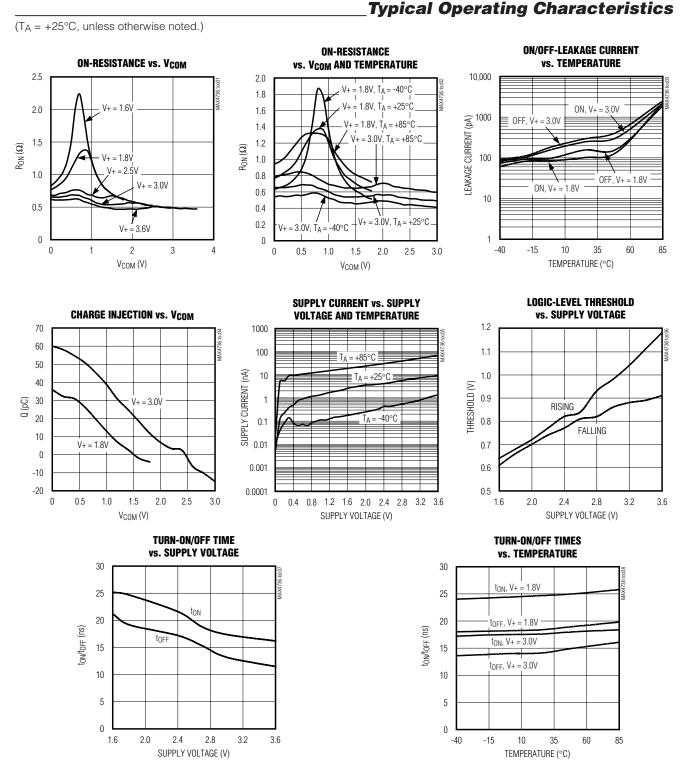
Note 6: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Guaranteed by design.

Note 8: Off-Isolation = $20\log_{10}(V_{COM_{-}}/V_{NO_{-}})$, $V_{COM_{-}}$ = output, $V_{NO_{-}}$ = input to OFF switch.

Note 9: Between two switches.

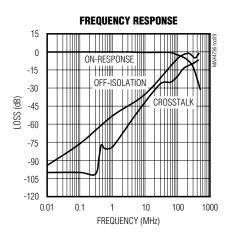
Note 10: Leakage parameters are 100% tested at hot temperature and guaranteed by correlation at room.

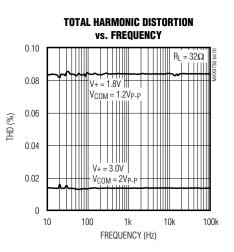


MAX4736

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 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$





Typical Operating Characteristics (continued)

Pin Description

Р	PIN		PIN NAME		FUNCTION		
μΜΑΧ	QFN	NAIVIE	FUNCTION				
1	12	IN1	Digital Control Input Switch 1				
2	1	NO1	Analog Switch 1—Normally Open Terminal				
3	2	GND	Ground				
4	3	NO2	Analog Switch 2—Normally Open Terminal				
5	4	IN2	Digital Control Input Switch 2				
6	5	COM2	Analog Switch 2—Common Terminal				
7	7	NC2	Analog Switch 2—Normally Closed Terminal				
8	8	V+	Positive-Supply Voltage Input				
9	9	NC1	Analog Switch 1—Normally Closed Terminal				
10	11	COM1	Analog Switch 1—Common Terminal				
	6, 10	N.C.	No Connection				

Detailed Description

The MAX4736 is a low 0.8Ω max (at V+ = 2.7V) onresistance, low-voltage, dual SPDT analog switch that operates from a 1.6V to 3.6V single supply. CMOS switch construction allows switching analog signals that range from GND to V+.

When powered from a 2.7V supply, the 0.8 Ω max R_{ON} allows high continuous currents to be switched in a variety of applications.

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings; stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO_, NC_, or COM_.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A 0.1μ F capacitor, connected from V+ to GND, is adequate for most applications.

Logic Inputs

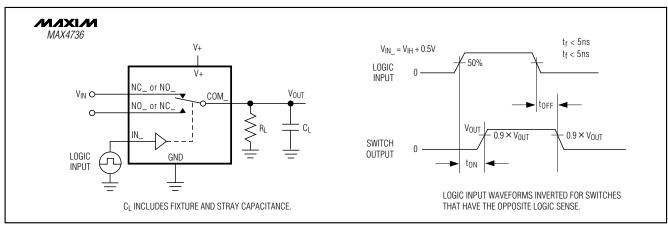
The MAX4736 logic inputs can be driven up to 3.6V, regardless of the supply voltage. For example, with a 1.8V supply, IN_ can be driven low to GND and high to 3.6V. Driving IN_ rail-to-rail minimizes power consumption.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO_, NC_, and COM_ pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.



Test Circuits/Timing Diagrams

Figure 1. Switching Time

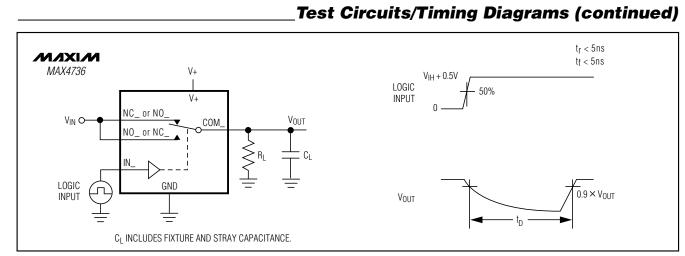


Figure 2. Break-Before-Make Interval

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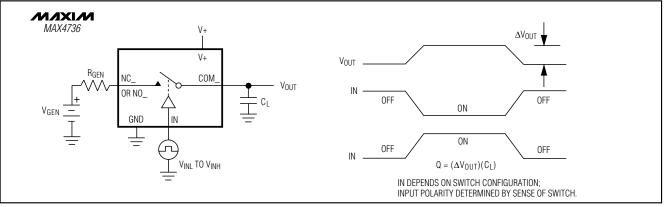


Figure 3. Charge Injection

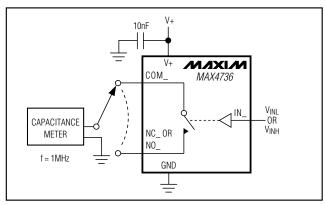


Figure 4. Channel Off/On-Capacitance

Chip Information

TRANSISTOR COUNT: 379 PROCESS: CMOS

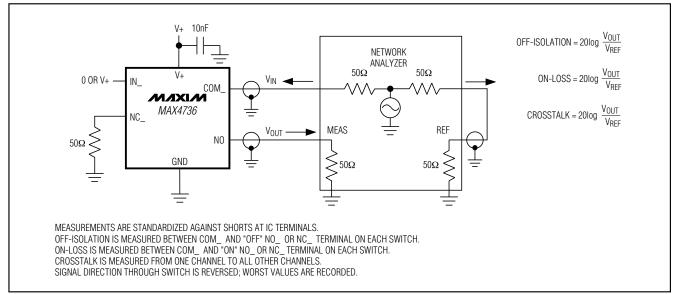
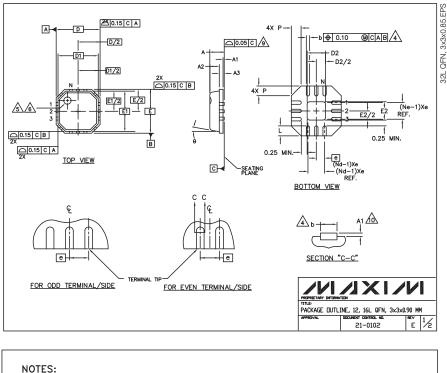


Figure 5. On-Loss, Off-Isolation, and Crosstalk

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



A A1 A2 A3

DDEE 0P

<u>3.00</u>

//////////// PACKAGE DUTLINE, 12, 16L QFN, 3x3x0.90 MM

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E 2/2

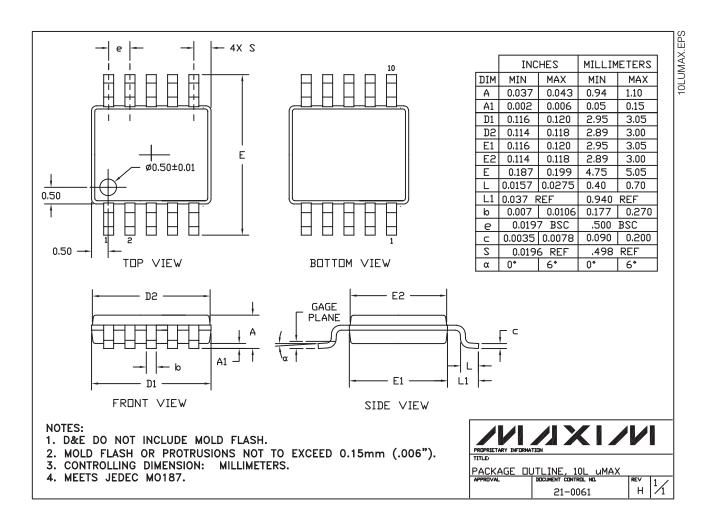
- 1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM (.012 INCHES MAXIMUM) DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. - 1994.
- A IS THE NUMBER OF TERMINALS. No IS THE NUMBER OF TERMINALS IN X-DIRECTION & No IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
- 4. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.
- 5. THE PIN #1 IDENTIFIER MUST EXIST ON THE TOP SURFACE OF THE PACKAGE BY USING INDENTATION MARK OR INK/ LASER MARKED.
- 6 EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL. 7. ALL DIMENSIONS ARE IN MILLIMETERS.
- 8. PACKAGE WARPAGE MAX 0.05mm.
- 9. APPLIED FOR EXPOSED PAD AND TERMINALS. EXCLUDE EMBEDDING PART OF EXPOSED PAD FROM MEASURING.
- MEETS JEDEC MO220.
- 11. THIS PACKAGE OUTLINE APPLIES TO ANVIL SINGULATION (STEPPED SIDES) AND TO SAW SINGULATION (STRAIGHT SIDES) QFN STYLES.

	MIN.	VARIAT NOM.	MAX.	No ₇	^ଲ ୍ଚ	MIN.	VARIAT	MAX.	Νοτε
e		0.50 BSC			e		0.50 BSC		
N		12		3	N		16		3
Nd		3		3	Nd		4		3
Ne		3		3	Ne		4		3
ιT	0.35	0.55	0.75		L	0.30	0.40	0.50	
b	0.18	0.23	0.30	4	Ь	0.18	0.23	0.30	4

М	ЛХ	
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Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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